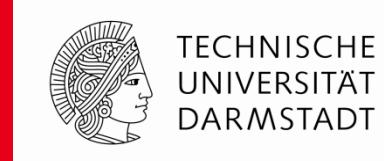


Outlook on SIBC Implementation in Time-Domain Wakefield Calculations



Andranik Tsakanian
TU Darmstadt, TEMF

TEMF – DESY Collaboration Meeting

09 July 2014
DESY, Hamburg



Contents



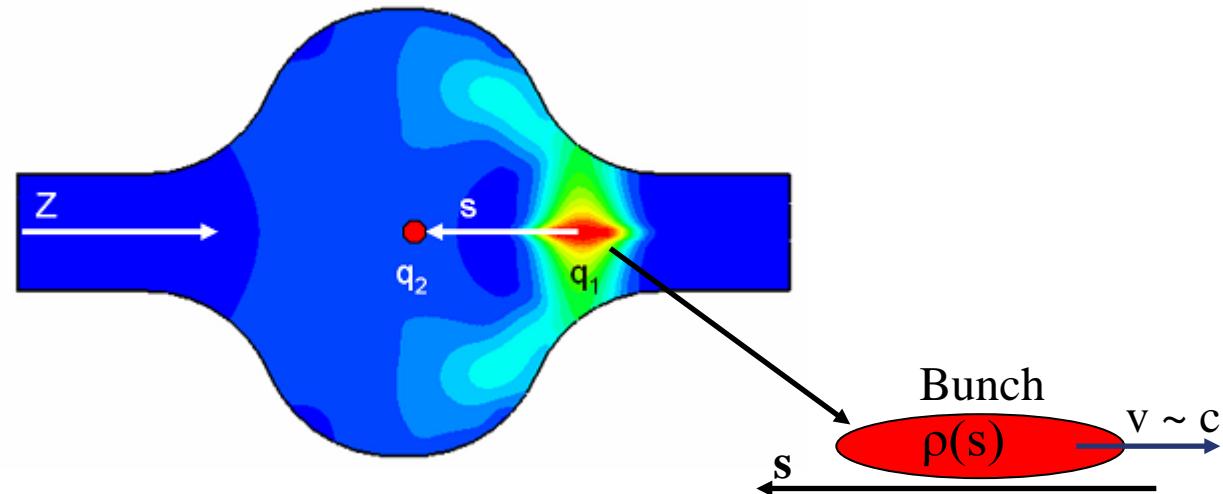
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- **Introduction**
- **Physical and numerical motivations**
- **SIBC in time domain**
- **Dispersion free numerical methods**
- **Applications**

Introducion



Wakefields and wake potentials



$$\vec{W}(s, \vec{r}_\perp^{(q_2)}) = \frac{1}{q_1} \int_{-\infty}^{+\infty} (\vec{E} + \vec{v} \times \vec{B}) \Big|_{t=\frac{z+s}{c}} dz$$

$\Delta \vec{p}^{(q_2)} \sim \vec{W}(s, \vec{r}_\perp^{(q_2)})$

Energy Loss
Transverse Kick

Bunch
 $\rho(s)$

Wakefields

Geometric

Resistive

Physical Motivation



Example: X-Ray SASE FELs

Requirements on electron beam

- Electron beam emittance

$$\varepsilon < \frac{\lambda_r}{4\pi}$$

(Overlapping of electron and photon beams in phase space)

- Relative energy spread (typical)

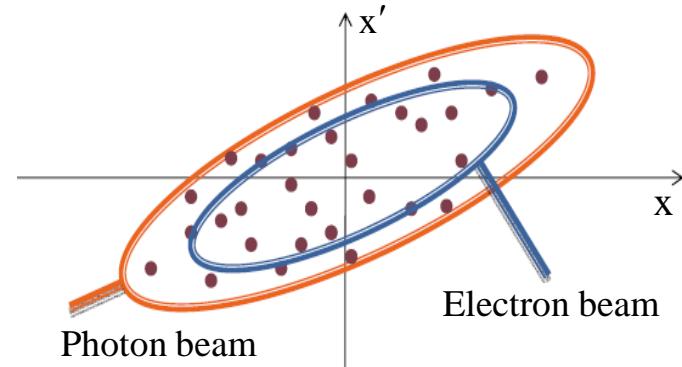
$$\frac{\Delta E}{E} \sim 10^{-4}$$

(To prevent widening of the spontaneous radiation line)

- High peak current \rightarrow Short bunches

The wakefields of short bunches

- Emittance growth \rightarrow
- Extra induced energy spread
- Degradation of FEL process



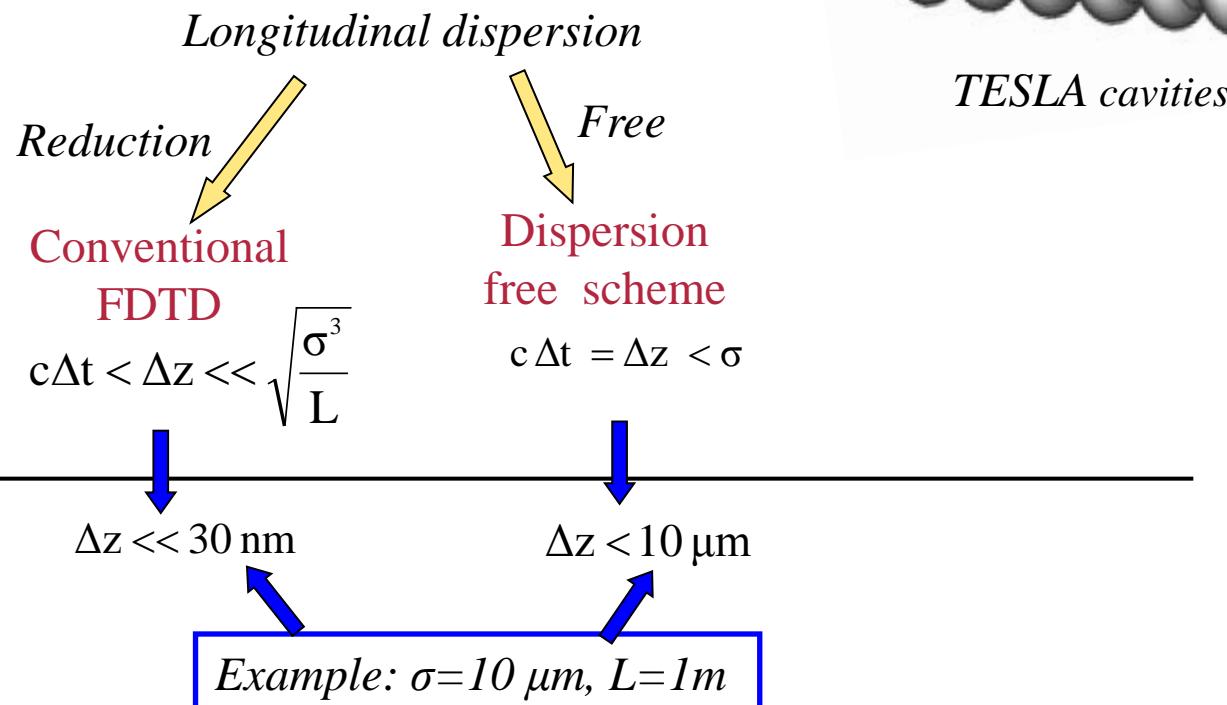
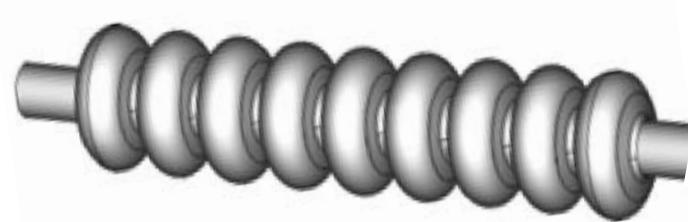
European XFEL

$\varepsilon_n \sim 1.4 \mu\text{m}$
$E \sim 17.5 \text{ GeV}$
$\sigma_b \sim 25 \mu\text{m}$
$\lambda_r \sim 0.1 \text{ nm}$

Numerical Motivation



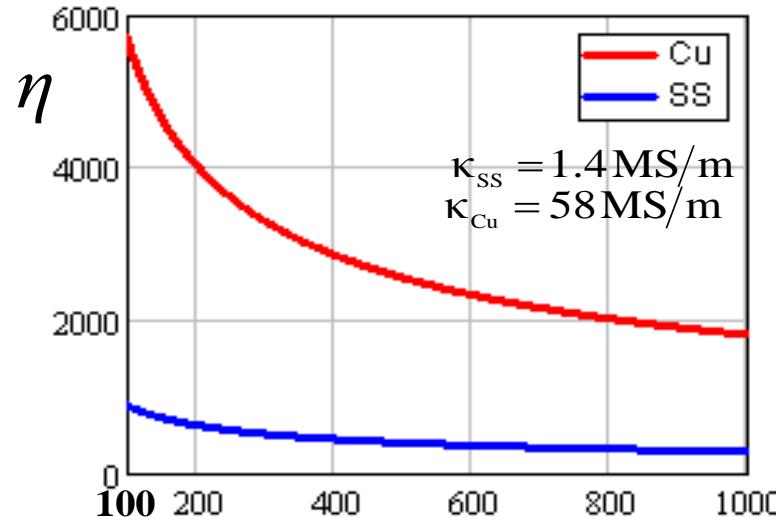
Why dispersion free numerical method?



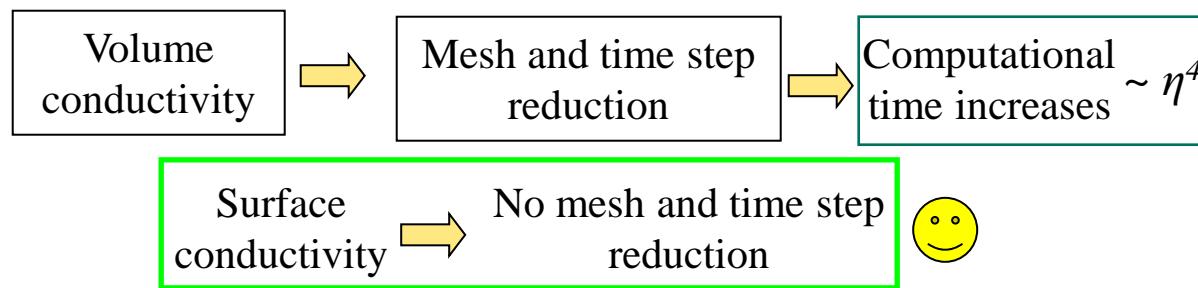
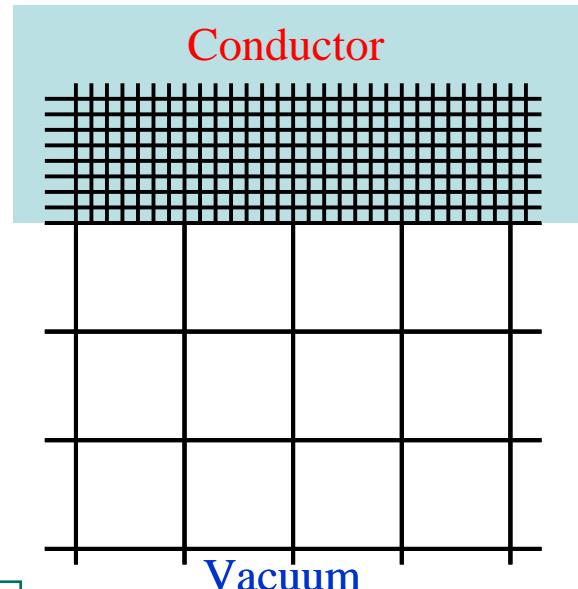
Numerical Motivation



Why we need surface impedance model ?



$$\eta \equiv \frac{\lambda_{\text{vacuum}}}{\lambda_{\text{metal}}} \sim \sqrt{\frac{c}{\omega} Z_0 \kappa}$$



SIBC in Time Domain



SIBC in Frequency Domain

$$\vec{E}_\tau(\omega) = Z_s(\omega) [\vec{n} \times \vec{H}_\tau(\omega)]$$

Transformation to TD

Rational function approximation

$$Z_s(\omega) \approx \alpha_0 + \sum_{i=1}^N \frac{\alpha_i}{j\omega - \beta_i}$$

SIBC in Time Domain

$$\vec{E}_\tau(t) = \sum_{i=0}^N \vec{G}_i(t)$$

Auxiliary Differential Equations

$$\begin{aligned}\vec{G}_0 &= \alpha_0 [\vec{n} \times \vec{H}_\tau] \\ \frac{d}{dt} \vec{G}_i - \beta_i \vec{G}_i &= \alpha_i [\vec{n} \times \vec{H}_\tau]\end{aligned}$$

- K. S. Oh and J. E. Schutt-Aine, An Efficient Implementation of SIBC for the FDTD Method, *IEEE Trans. Antennas Propagat.*, vol. 43, pp. 660–666, 1995.
- Riku M. Mäkinen, An Efficient SIBC for Thin Wires of Finite Conductivity, *IEEE Trans. Antennas Propagat.*, vol. 52, pp. 3364-3372 , 2004
- R. Mäkinen, T. Lau, E. Gjonaj, T. Weiland, Computation of Resistive Wakefield with the PBCI Code, *Proceedings of EPAC08*, Genoa, Italy, 2008, pp. 1753-1755

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Semi-Discrete Maxwell's Equations with SIBC

$$\frac{d}{dt} \begin{pmatrix} \hat{e} \\ \hat{h} \\ 0 \\ G_1 \\ \vdots \\ G_N \end{pmatrix} = \begin{pmatrix} 0 & M_\varepsilon^{-1} C^T & 0 & 0 & \cdots & 0 \\ -M_\mu^{-1} C & 0 & C_B & C_B & \cdots & C_B \\ 0 & -\alpha_0 & 1 & 0 & \cdots & 0 \\ 0 & \alpha_1 & 0 & \beta_1 & \cdots & 0 \\ \vdots & \vdots & \vdots & \vdots & \ddots & \vdots \\ 0 & \alpha_N & 0 & 0 & \cdots & \beta_N \end{pmatrix} \begin{pmatrix} \hat{e} \\ \hat{h} \\ G_0 \\ G_1 \\ \vdots \\ G_N \end{pmatrix}$$

Boundary Effects



$$Z_s(\omega) = Z_s^\sigma(\omega) + Z_s^L(\omega)$$

• **Finite Resistivity**

$$Z_s^\sigma(\omega) \approx \sqrt{\frac{j\omega\mu}{\sigma(\omega) + j\omega\epsilon}}$$
$$\sigma(\omega) \approx \frac{\sigma_0}{1 + j\omega\tau}$$

• **Surface Roughness**
• **Metal Oxidation**

$$Z_s^L(\omega) \approx j\omega L$$
$$L \approx \mu_0 \left[\frac{\epsilon_r - 1}{\epsilon_r} \cdot \Delta_{oxide} + 0.01 \cdot \Delta_{rough} \right]$$

$\epsilon_r \sim 10$ $\Delta_{oxide} \sim 7 \text{ nm}$

$\Delta_{rough} \sim 500 \text{ nm}$

- M. Dohlus. TESLA report 2001-26, 2001
- K. Bane, G. Stupakov, SLAC-PUB-10707, 2004
- A. Tsakanian, M. Dohlus, I. Zagorodnov, TESLA-FEL-2009-05, 2009

Dispersion-Free Numerical Methods



FIT

LT Splitting Scheme

$$\begin{aligned}\oint_S \vec{E} \cdot d\vec{l} &= -\frac{\partial}{\partial t} \int_S \mu \vec{H} \cdot d\vec{A} \\ \oint_S \vec{H} \cdot d\vec{l} &= \int_S \left[\vec{J} + \frac{\partial}{\partial t} \varepsilon \vec{E} \right] \cdot d\vec{A} \\ \oint_V \varepsilon \vec{E} \cdot d\vec{A} &= \int_V \rho \, dV \\ \oint_V \mu \vec{H} \cdot d\vec{A} &= 0\end{aligned}$$

Strang Splitting

$$\begin{pmatrix} \hat{e} \\ h \end{pmatrix}^{n+1} = G_t \left(\frac{\Delta t}{2} \right) G_l (\Delta t) G_t \left(\frac{\Delta t}{2} \right) \begin{pmatrix} \hat{e} \\ h \end{pmatrix}^n$$

Dispersion-free in longitudinal direction

FVTD Scheme

$$\begin{aligned}\oint_V \vec{E} \times d\vec{A} &= -\frac{\partial}{\partial t} \int_V \mu \vec{H} \, dV \\ \oint_V \vec{H} \times d\vec{A} &= \int_V \left[\vec{J} + \frac{\partial}{\partial t} \varepsilon \vec{E} \right] dV \\ \oint_V \varepsilon \vec{E} \cdot d\vec{A} &= \int_V \rho \, dV \\ \oint_V \mu \vec{H} \cdot d\vec{A} &= 0\end{aligned}$$

$$\begin{pmatrix} e \\ h \end{pmatrix}^{n+1} = G(\Delta t) \begin{pmatrix} e \\ h \end{pmatrix}^n$$

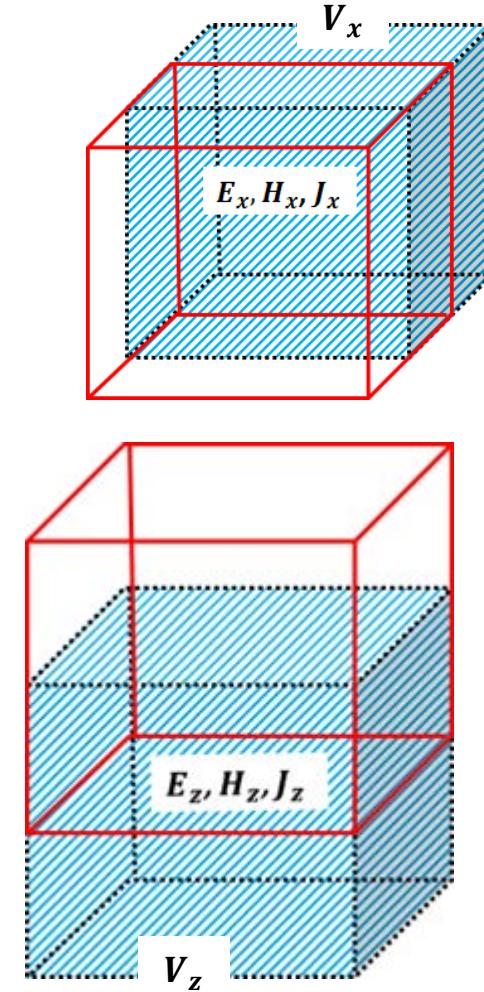
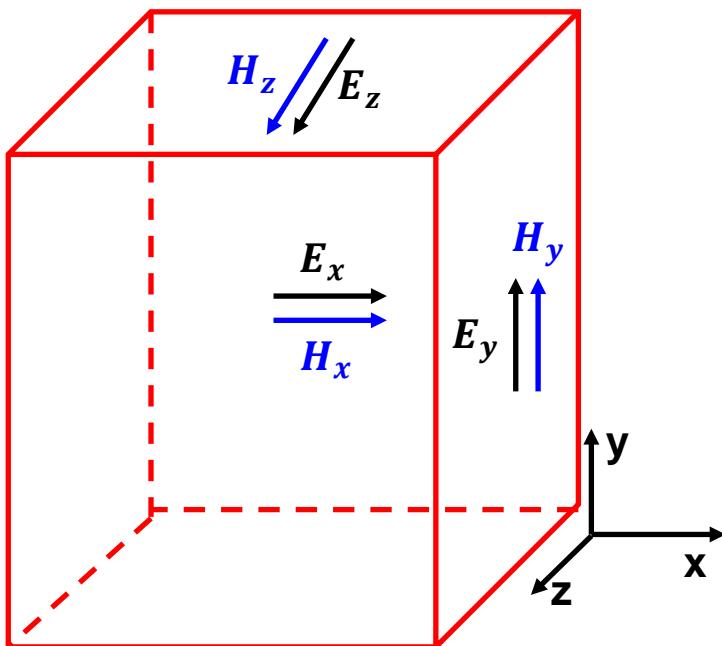
No Splitting

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- E. Gjonaj, T. Lau, T. Weiland, Wakefield Computation with the PBCI Code using a Non-Split Finite Volume Method, Proceedings of PAC09, Vancouver, Canada, 2009, pp. 4516-4518

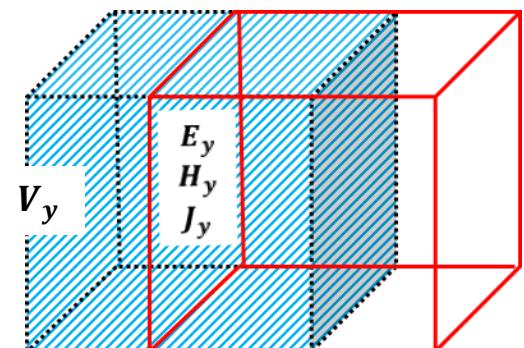
Finite Volume Time Domain Method



Allocations of E&M Field Components on Cartesian Grid



$$\frac{\partial}{\partial t} \int_V \mu \vec{H} dV = - \oint_{\partial V} \vec{E} \times d\vec{A}$$
$$\frac{\partial}{\partial t} \int_V \epsilon \vec{E} dV = \oint_{\partial V} \vec{H} \times d\vec{A} - \int_V \vec{J} dV$$

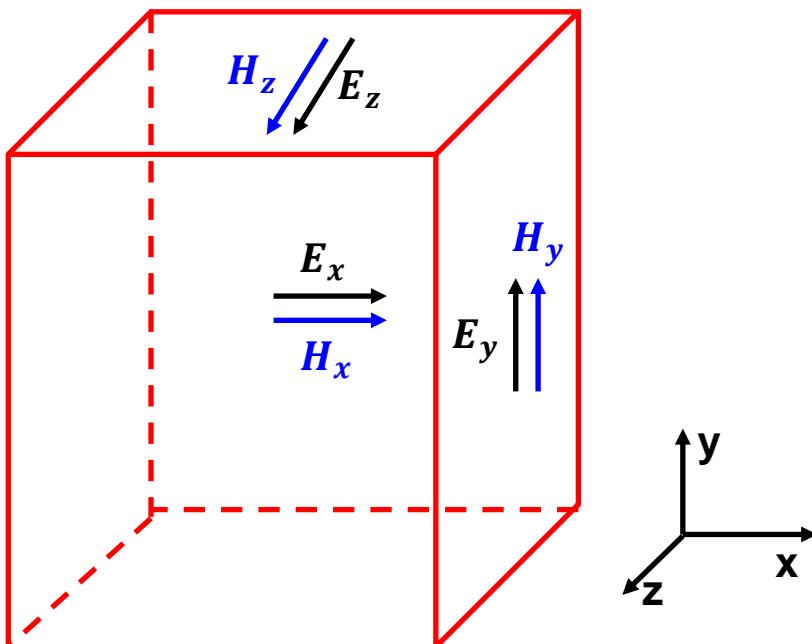


V_x, V_y, V_z
Control Volumes

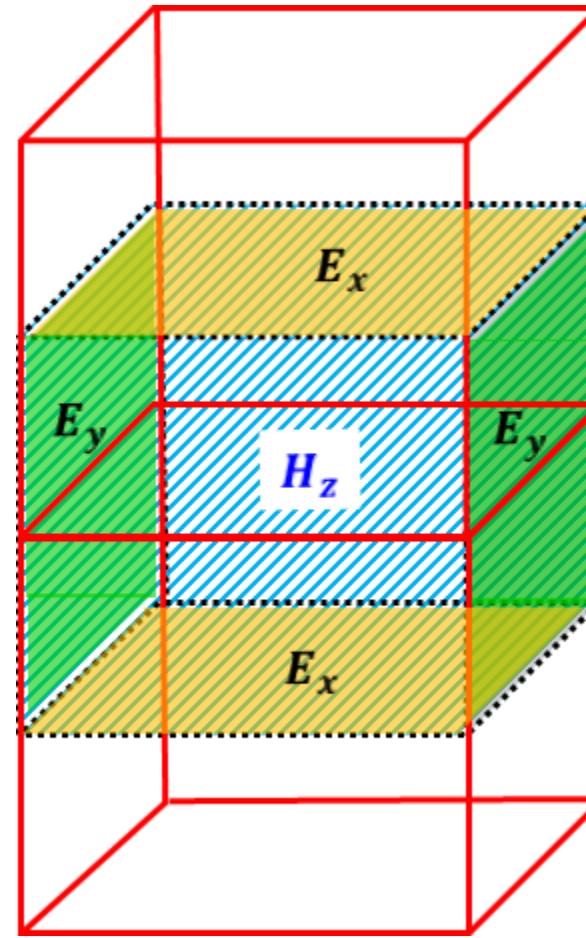
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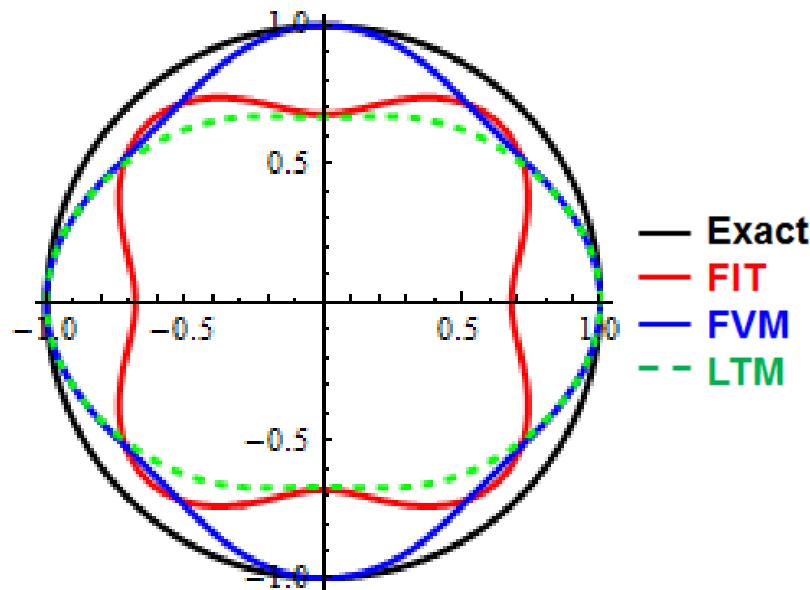


Dispersion Properties of Numerical Methods



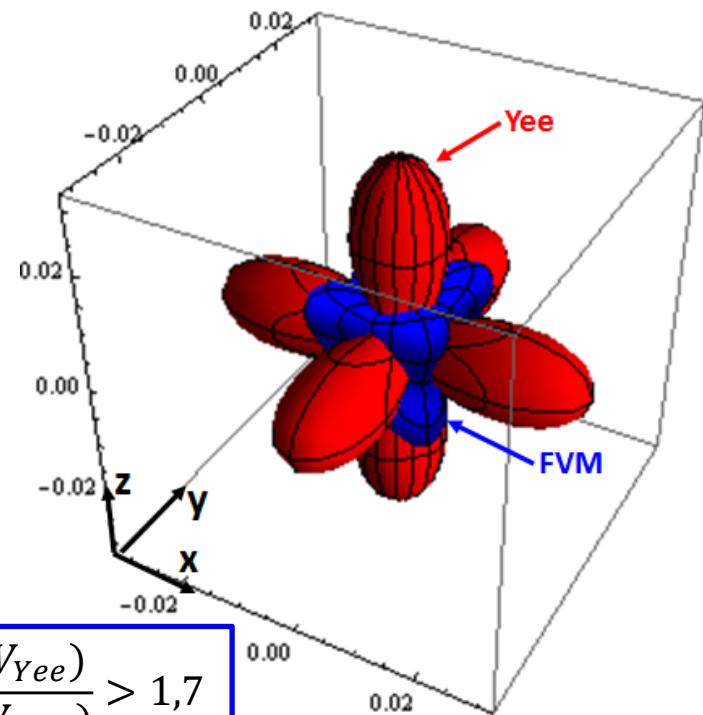
Numerical phase velocity
vs propagation direction

2D – $\Delta = \lambda/2$



Numerical phase velocity error
vs propagation direction

3D – $\Delta = \lambda/6$



$$\frac{\max(\Delta V_{Yee})}{\max(\Delta V_{FVM})} > 1,7$$

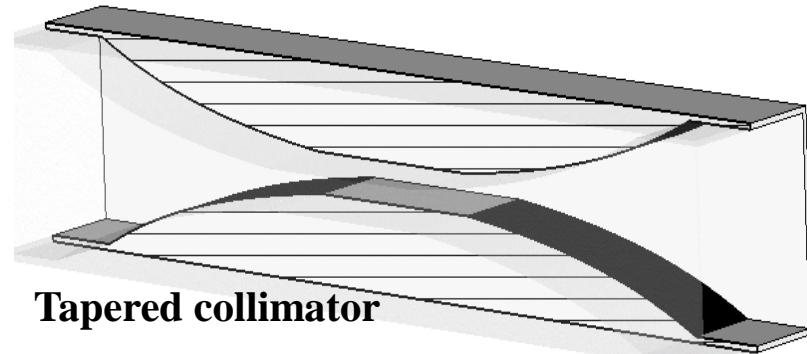
Applications



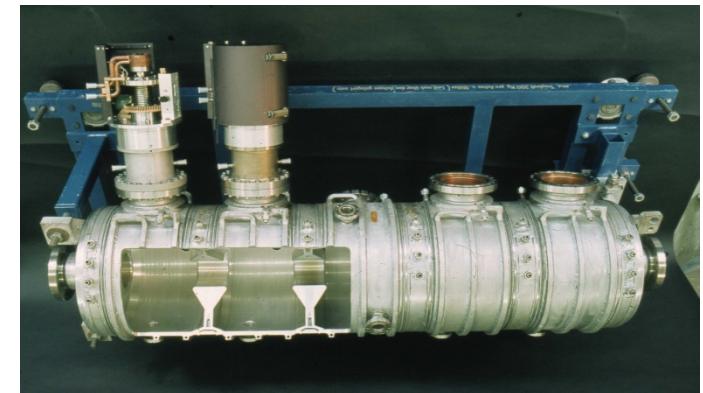
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Resistive wake field calculations of ultra short bunches in various structures:

- Collimators
- Undulator beampipe (Elliptical)
- Undulator intersections
- Warm accelerating structures
- Multi-layer structures (check SIBC model)
- Etc.



Tapered collimator



PETRA cavity

Thank You for Your Attention!